

Two Channels: 2 x $100m\Omega$

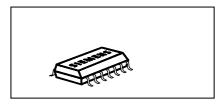
Status Feedback Suitable for 42V

Product Summary

Operating Voltage	$V_{bb(on)}$	7.0 58V		
	Active channels	One	two parallel	
On-state Resistance	R _{on}	105m $Ω$	$53 m\Omega$	
Nominal load current	I _{L(NOM)}	2.9A	4.2A	
Current limitation	I _{L(SCr)}	8A	8A	



Package



PG-DSO14

General Description

- N channel vertical power MOSFET with charge pump, ground referenced CMOS compatible input and diagnostic feedback, monolithically integrated in Smart SIPMOS® 80V technology.
- Providing embedded protective functions
- An array of resistors is integrated in order to reduce the external components

Applications

- μC compatible high-side power switch with diagnostic feedback for 12V and 24V and 42V grounded loads
- All types of resistive, inductive and capacitive loads
- Most suitable for inductive loads
- Replaces electromechanical relays, fuses and discrete circuits

Basic Functions

- CMOS compatible input
- Improved electromagnetic compatibility (EMC)
- Fast demagnetization of inductive loads
- Stable behaviour at undervoltage
- Wide operating voltage range
- Logic ground independent from load ground
- Optimized inverscurrent capability

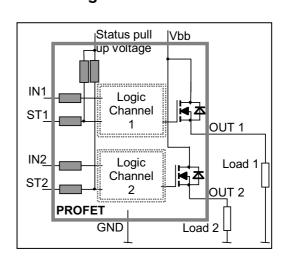
Protection Functions

- Short circuit protection
- Overload protection
- **Current limitation**
- Thermal shutdown
- Overvoltage protection (including load dump) with external resistor
- Reverse battery protection with external resistor
- Loss of ground and loss of V_{bb} protection
- Electrostatic discharge protection (ESD)

Diagnostic Function

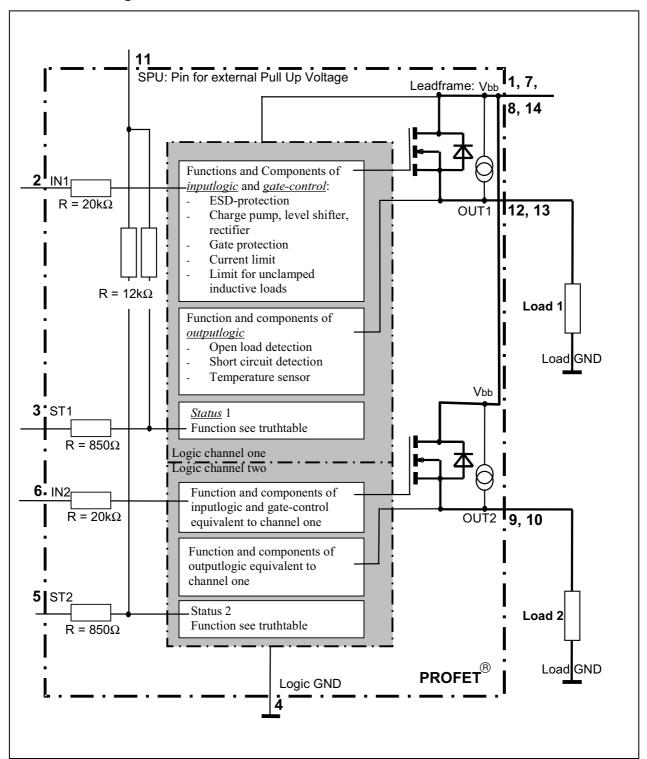
- Diagnostic feedback with open drain output and integrated pull up resistors
- Open load detection in OFF-state
- Feedback of thermal shutdown in ON-state
- Diagnostic feedback of both channels works properly in case of inverse current

Block Diagram





Functional diagram

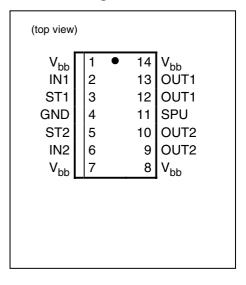




Pin Definitions and Functions

	1	
Pin	Symbol	Function
		Positive power supply voltage. Design the
1,7,	.,	wiring for the simultaneous max. short circuit
8,14,	· · · V L L	currents from channel 1 to 2 and also for low
, ,		thermal resistance
2	IN1	Input 1,2 activates channel 1,2 in case
6	IN2	of logic high signal
12,13	OUT1	Output 1,2 protected high-side power output
		of channel 1,2. Design the wiring for the max.
	OUT2	short circuit current; both outputpins have to be
9,10		connected in parallel for operation according
		this spec.
3	ST1	Diagnostic feedback 1,2 of channel 1,2
5	ST2	open drain
4	GND	Logic Ground
		Connection for external pull up voltage source
11	SPU	for the open drain status output.
		Pull up resistors are integrated.

Pin configuration





Parameter	Symbol	Values	Unit
Supply voltage (overvoltage protection see page 6)	$V_{ m bb}$	58	V
Supply voltage for full short circuit protection $T_{j,\text{start}} = -40 \dots +150^{\circ}\text{C}$	$V_{ m bb}$	50	V
Output Voltage to V _{bb}	V _{ON}	70	V
Negative voltage slope at output	$-dV_{OUT}/dt$	20	V/µs
Load current (Short-circuit current, see page 7)	/ ∟	/ _{L(LIM)} 1)	Α
Load dump protection ²⁾ $V_{\text{LoadDump}} = V_{\text{A}} + V_{\text{S}}, V_{\text{A}} = 27 \text{ V}$ $R_{\text{I}^3} = 8 \Omega, t_{\text{d}} = 200 \text{ms}; \text{ IN} = \text{low or high,}$ each channel loaded with $R_{\text{L}} = 20 \Omega,$	V _{Load dump} ⁴⁾	70	V
Operating temperature range Storage temperature range	$T_{ m stg}$	-40+150 -55+150	°C
Power dissipation (DC) ⁵⁾ $T_a = 25$ °C: (all channels active) $T_a = 85$ °C:	P _{tot}	3.0 1.6	W
Maximal switchable inductance, single pulse $V_{bb} = 12V$, $T_{j,start} = 150^{\circ}C^{5}$,			
$I_{\rm L}$ = 2.5 A, $E_{\rm AS}$ = 110 mJ, 0 Ω one channel: $I_{\rm L}$ = 3.5 A, $E_{\rm AS}$ = 278 mJ, 0 Ω two parallel channels: see diagrams on page 12	Z_{L}	23.0 30.0	mH
Electrostatic discharge capability (ESD): (Human Body Model) acc. MIL-STD883D, method 3015.7 and ESD assn. std. S5.1-1993 R=1.5kΩ; C=100pF	V _{ESD}	1.0	kV
Input voltage (DC)	V_{IN}	±42	V
Current through input pin (DC)	I _{IN}	±2.0	mA
Current through status pin (DC)	I _{ST}	±2.0	
Status pull up voltage	V _{SPU}	±42	V

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¹⁾ Current limit is a protection function. Operation in current limitation is considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

Supply voltages higher than $V_{bb(AZ)}$ require an external current limit for the GND and status pins (a 150 Ω resistor for the GND connection is recommended.

³⁾ $R_{\rm I}$ = internal resistance of the load dump test pulse generator

⁴⁾ V_{Load dump} is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839

⁵⁾ Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6cm² (one layer, 70μm thick) copper area for V_{bb} connection. PCB is vertical without blown air. See page 15



Parameter and Conditions		Symbol	Values			Unit
			min	typ	Max	
Thermal resistance junction - soldering point ^{5),6)} junction - ambient ⁵⁾	each channel: one channel active: all channels active:	R _{thjs} R _{thja}	 	 45 41	25 	K/W

Electrical Characteristics

Parameter and Conditions, each of the two channels	Symbol		Values	}	Unit
at $T_j = -40+150$ °C, $V_{bb} = 24$ V unless otherwise specified		min	typ	Max	

Load Switching Capabilities and Characteristics

On-state resistance (V_{bb} to OUT); $I_L = 2 \text{ A}, V_{bb} \ge 7V$				
each channel, $T_i = 25^{\circ}\text{C}$:	R_{ON}	 90	105	mΩ
<i>T</i> _j = 150°C:		 170	210	
two parallel channels, $T_i = 25^{\circ}$ C:		 45	53	
see diagram, page 12				

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⁶⁾ Soldering point: Upper side of solder edge of device pin 15. See page 15



Parameter and Conditions, each of the two channels	Symbol		Values	i	Unit
at $T_j = -40+150$ °C, $V_{bb} = 24$ V unless otherwise specified		min	typ	Max	
Nominal load current one channel active: two parallel channels active:	I _{L(NOM)}	2.5 4.0	2.9 4.2		А
Device on PCB ⁷), $T_a = 85^{\circ}\text{C}$, $T_j \le 150^{\circ}\text{C}$					
Output current while GND disconnected or pulled up $^{8)}$; $V_{bb} = 30 \text{ V}$, $V_{IN} = 0$,	I _{L(GNDhigh)}			1.0	mA
see diagram page 11					
Turn-on time ⁹⁾ Turn-off time $R_{\rm I} = 12 \Omega$ IN to 90% $V_{\rm OUT}$: to 10% $V_{\rm OUT}$:	$t_{ m on} \ t_{ m off}$			55 95	μs
Slew rate on 9)	dV/dt_{on}	1.0		5	V/μs
10 to 30% V_{OUT} , $R_{\text{L}} = 12 \Omega$:	a v a ton	1.0		Ū	ν/μο
Slew rate off ⁹⁾ 70 to 40% V_{OUT} , $R_{\text{L}} = 12 \Omega$:	-d <i>V</i> /d <i>t</i> _{off}	1.0		5	V/µs

Operating Parameters

Operating voltage	V _{bb(on)}	7.0		58	V
Undervoltage restart of charge pump					
Τ̄ _j =-40+25°C: Τ _i =+150°C:	$V_{ m bb(ucp)}$		4	5.5	V
$T_{\rm j} = +150^{\circ}{\rm C}$:				7.0	
Overvoltage protection ¹⁰⁾	$V_{ m bb(AZ)}$	58.5	63	69	٧
$I_{bb} = 40 \text{ mA}$,				
Standby current ¹¹) $T_i = -40^{\circ}\text{C} + 25^{\circ}\text{C}$:	I _{bb(off)}		13	23	μA
Standby current ¹¹) $T_j = -40^{\circ}\text{C} + 25^{\circ}\text{C}$: $V_{\text{IN}} = 0$; see diagram page 10 $T_j = +125^{\circ}\text{C}^{12}$: $T_j = +150^{\circ}\text{C}$:	22(0)			23	•
$V_{IN} = 0$; see diagram page 10 $T_j = +150$ °C:			25	35	
Off-State output current (included in <i>I</i> _{bb(off)})	I _{L(off)}		3		μΑ
$V_{\rm IN}$ = 0; each channel	_(,				•
Operating current ¹³⁾ , $V_{IN} = 5V$,					
one channel on:	I _{GND}		1.0	1.5	mΑ
all channels on:			2.0	3.0	

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Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6cm 2 (one layer, 70 μ m thick) copper area for V_{bb} connection. PCB is vertical without blown air. See page 15

⁸) not subject to production test, specified by design

⁹⁾ See timing diagram on page 13.

Supply voltages higher than $V_{bb(AZ)}$ require an external current limit for the GND; a 150 Ω resistor is recommended. See also $V_{ON(CL)}$ in table of protection functions and circuit diagram on page 10.

¹¹⁾ Measured with load; for the whole device; all channels off

¹²) not subject to production test, specified by design

¹³⁾ Add I_{ST} , if $I_{ST} > 0$



Parameter and Conditions, each of the two channels	Symbol	Values		Unit	
at T _j = -40+150°C, V_{bb} = 24 V unless otherwise specified		min	typ	Max	
Protection Functions ¹⁴⁾					
Current limit, (see timing diagrams, page 13)					
<i>T</i> _j =-40°C:	I _{L(lim)}		10	12	Α
$T_{j} = -40^{\circ}\text{C}:$ $T_{j} = 25^{\circ}\text{C}:$ $T_{j} = +150^{\circ}\text{C}:$		5	9 8		
Repetitive short circuit current limit 15),					
$T_{\rm j} = T_{\rm jt}$ each channel	I _{L(SCr)}		8		Α
two parallel channels (see timing diagrams, page 13)			8		
Initial short circuit shutdown time $T_{i,start} = 25^{\circ}C$:	t _{off(SC)}		2		ms
(see timing diagrams on page 13)					
Output clamp (inductive load switch off) ¹⁶⁾					
at VON(CL) = Vbb - VOUT, IL = 1 A	V _{ON(CL)}	59	64	70	V
Thermal overload trip temperature	$ T_{jt} $	150			°C
Thermal hysteresis	$\Delta T_{\rm jt}$		10		K
Reverse Battery					
Reverse battery voltage ¹⁷)	- V _{bb}			24	V
Drain-source diode voltage ($V_{out} > V_{bb}$) ¹⁸⁾ $I_L = -3.0 \text{ A}, T_j = +150^{\circ}\text{C}$	-V _{ON}		650		mV
Inverse current 19)					
GND current in case of 3A inverse current ²⁰)	I _{GND(inv cur)}			15	mA

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¹⁴⁾ Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

¹⁵) not subject to production test, specified by design

¹⁶⁾ If channels are connected in parallel, output clamp is usually accomplished by the channel with the lowest V_{ON(CL)}

Requires a 150 Ω resistor in GND connection. The reverse load current through the intrinsic drain-source diode has to be limited by the connected load. Power dissipation is higher compared to normal operating conditions due to the voltage drop across the drain-source diode. The temperature protection is not active during reverse current operation! Input and Status currents have to be limited (see max. ratings page 4 and circuit page 10).

¹⁸) not subject to production test, specified by design

¹⁹) not subject to production test, specified by design

²⁰⁾ In case of an inverse current of 3A the both status outputs must not be disturbed.

The neighbour channel can be switched normally; not all paramters lay within the range of the spec Please note, that in case of an inverse current no protection function is active. The power dissipation is higher compared to normal operation in forward mode due to the voltage drop across the drain-source diode

10

5.4

25

6.1

50

0.4

٧



On state input current

Zener limit voltage

Status low voltage

Status output (open drain)

Parameter and Conditions, each	of the two channels	Symbol		Values	1	Unit
at T _j = -40+150°C, V_{bb} = 24 V unless of	therwise specified		min	typ	Max	
Diagnostic Characteristics						
Open load detection current ²¹⁾		I _{L(off)}		3		μΑ
Open load detection voltage		V _{OUT(OL)}	2.0	2.85	3.7	V
Short circuit detection voltage ²²⁾ V _{bb} (pin 1,7,8,14) to OUT1 (pin 12) V _{bb} (pin 1,7,8,14) to OUT2 (pin 9)	V _{ON(SC)}		4.0		V	
Input and Status Feedback ²³⁾						
Integrated resistors; $T_j = 25$ °C:	Input	$R_{\rm l}$		20		kΩ
(see circuit page 2)	Status Status pull up	$egin{array}{c} R_{ST} \ R_{pull\ up} \end{array}$	0.53	0.85 12	1.2	kΩ kΩ
Input turn-on threshold voltage		$V_{\rm IN(T+)}$	1.2		2.2	V
Input turn-off threshold voltage		V _{IN(T-)}	1.0			V
Input threshold hysteresis		$\Delta V_{\text{IN(T)}}$		0.25		V
Off state input current $V_{IN} = 0.4 \text{ V}$:						

 $V_{IN} = 5 \text{ V}$:

 $V_{SPU} = 5V$:

 $I_{IN(on)}$

 $V_{\rm ST(high)}$

 $V_{\rm ST(low)}$

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²¹) not subject to production test, specified by design

²²) not subject to production test, specified by design

 $^{^{23)}}$ If a ground resistor R_{GND} is used, add the voltage drop across these resistors.

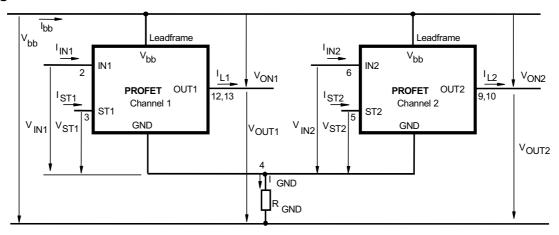


Truth Table

Channel 1	Input 1	Output 1	Status 1
Channel 2	Input 2	Output 2	Status 2
	level	level	BTS 723
Normal	L	L	L
operation	Н	Н	Н
Open load	L	$V_{OUT} > 2.7V$	Н
	Н	Н	Н
Short circuit	L	L	L
to GND	Н	L	L
Short circuit	L	Н	Н
to V _{bb}	Н	Н	Н
Overtem-	L	L	L
perature	Н	L	L

Parallel switching of channel 1 and 2 is easily possible by connecting the inputs and outputs in parallel. In this mode it is recommended to use only one status.

Terms



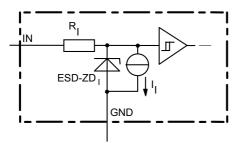
Leadframe (V_{bb}) is connected to pin 1,7,8,14

External R_{GND} optional; a single resistor R_{GND} = 150 Ω for reverse battery protection up to the max. operating voltage.

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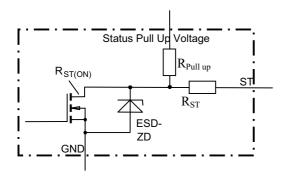


Input circuit (ESD protection), IN1 or IN2



The use of ESD zener diodes as voltage clamp at DC conditions is not recommended.

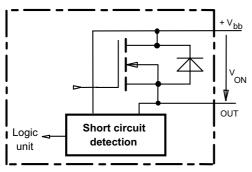
Status output, ST1 or ST2



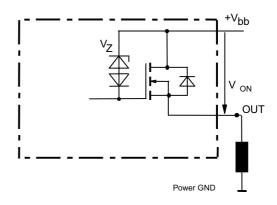
ESD-Zener diode: 6.1 V typ., $R_{ST(ON)}$ < 250 Ω , R_{ST} = 850 Ω typ., $R_{pull\ up}$ = 12 k Ω typ. The use of ESD zener diodes as voltage clamp at DC conditions is not recommended

Short Circuit detection

Fault Signal at ST-Pin: $V_{\rm ON} > 4.0$ V typ, no switch off by the PROFET itself, external switch off recommended!

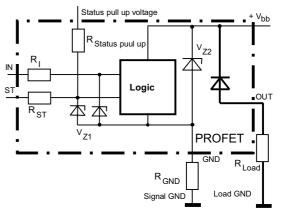


Inductive and overvoltage output clamp, OUT1 or OUT2



 V_{ON} clamped to $V_{ON(CL)} = 64 \text{ V typ.}$

Overvolt. and reverse batt. protection



 V_{Z1} = 6.1 V typ., V_{Z2} = 63 V typ., R_{GND} = 150 Ω, R_{I} = 850 Ω typ., R_{ST} = 20 kΩ typ., $R_{pull\ up}$ = 12 kΩ typ In case of reverse battery the load current has to be limited by the load. Temperature protection is not active

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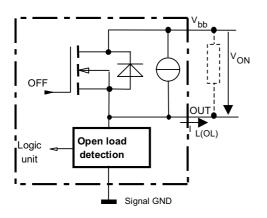
Open-load detection, OUT1 or OUT2

OFF-state diagnostic condition:

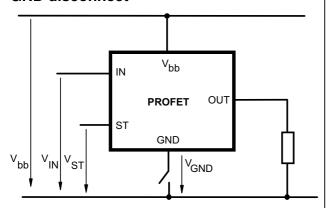
Open load, if $V_{OUT} > 2.7 \text{ V typ.}$ (IN low)

 $I_{\text{\tiny L(OL)}}$ typ. $2\mu A$

An external resitor can be used to increase the open load detection current



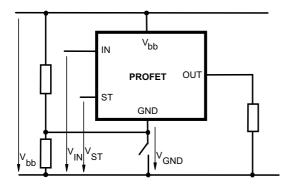
GND disconnect



Any kind of load.

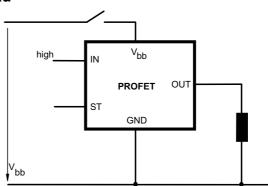
Due to $V_{GND} > 0$, no $V_{ST} = low signal available$.

GND disconnect with GND pull up



Any kind of load. If $V_{GND} > V_{IN} - V_{IN(T+)}$ device stays off Due to $V_{GND} > 0$, no $V_{ST} = low$ signal available.

V_{bb} disconnect with energized inductive load

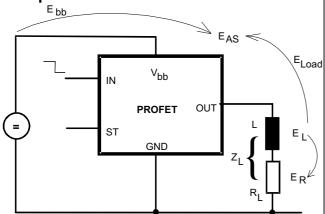


For inductive load currents up to the limits defined by Z_L (max. ratings and diagram on page 12) each switch is protected against loss of V_{bb} .

Consider at your PCB layout that in the case of Vbb disconnection with energized inductive load all the load current flows through the GND connection.



Inductive load switch-off energy dissipation



Energy stored in load inductance:

$$E_{\rm L} = \frac{1}{2} \cdot {\rm L} \cdot {\rm I}_{\rm L}^2$$

While demagnetizing load inductance, the energy dissipated in PROFET is

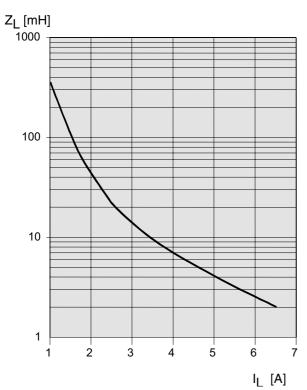
$$E_{AS} = E_{bb} + E_L - E_R = V_{ON(CL)} \cdot i_L(t) dt$$

with an approximate solution for $R_L > 0 \Omega$:

$$E_{AS} = \frac{I_L \cdot L}{2 \cdot R_L} \left(V_{bb} + |V_{OUT(CL)}| \right) \ln \left(1 + \frac{I_L \cdot R_L}{|V_{OUT(CL)}|} \right)$$

Maximum allowable load inductance for a single switch off (one channel)⁵⁾

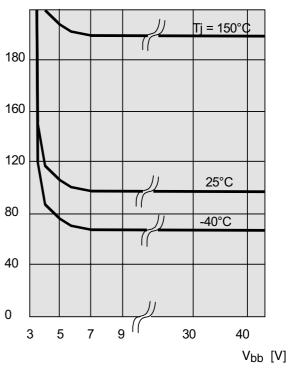
$$L = f(I_L)$$
; T_{j,start} = 150°C, V_{bb} = 12 V, R_L = 0 Ω



Typ. on-state resistance

 $R_{ON} = f(V_{bb}, T_i)$; L = 2 A, IN = high

RON [mOhm]



Typ. standby current

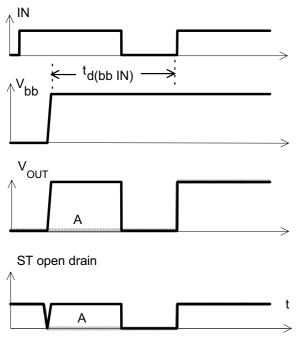
 $I_{bb(off)} = f(T_j)$; $V_{bb} = 9...34 \text{ V}$, IN1,2,3,4 = low



Timing diagrams

All channels are symmetric and consequently the diagrams are valid for channel 1 and channel 2

Figure 1a: V_{bb} turn on, :



in case of too early $V_{\rm IN}$ =high the device may not turn on (curve A) $t_{\rm d(bb\ IN)}$ approx. 150 μs

Figure 2a: Switching a resistive load, turn-on/off time and slew rate definition:

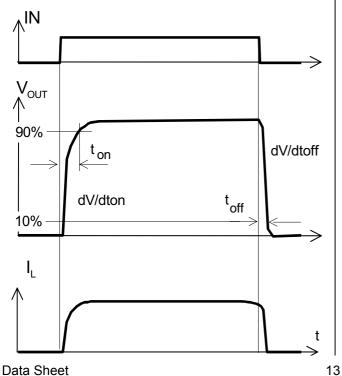


Figure 2b: Switching an inductive load

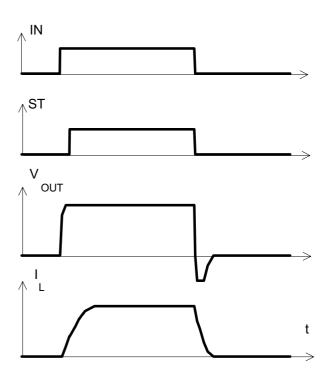


Figure 3a: Short circuit: shut down by overtempertature, reset by cooling

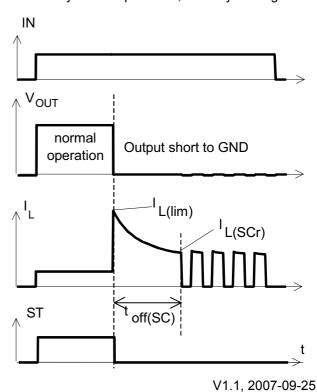




Figure 4a: Overtemperature: Reset if $T_j < T_{jt}$

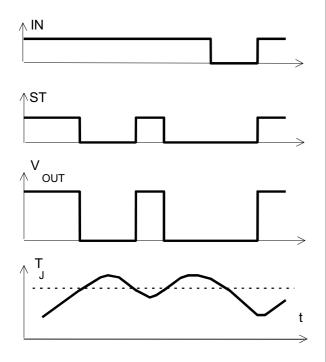


Figure 5a: Open load, : detection in OFF-state, open load occurs in off-state

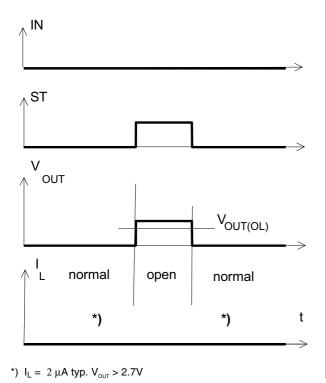
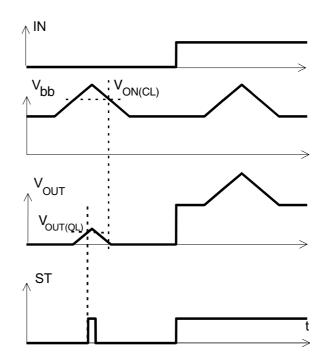


Figure 6: Overvoltage, no shutdown:





Package Outlines

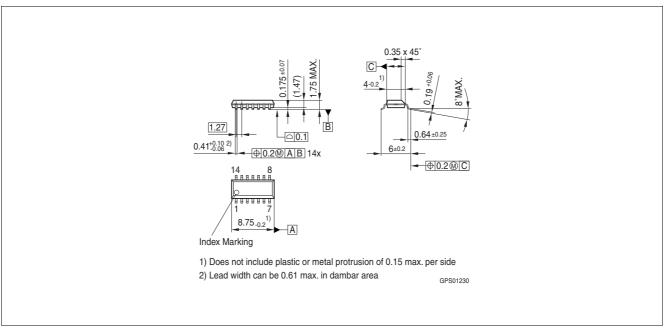


Figure 1 PG-DSO-14-37 (Plastic Dual Small Outline Package) (RoHS-compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

Please specify the package needed (e.g. green package) when placing an order



Revision History

Version	Date	Changes
V1.1	2007-09-25	Modification of the package drawing
V1.0	2007-05-25	Creation of the green datasheet.
		First page :
		Adding the green logo and the AEC qualified
		Adding the bullet AEC qualified and the RoHS compliant features
		Package page :
		Modification of the package to be green.

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